

## DF 91 Battery-type R.F. pentode

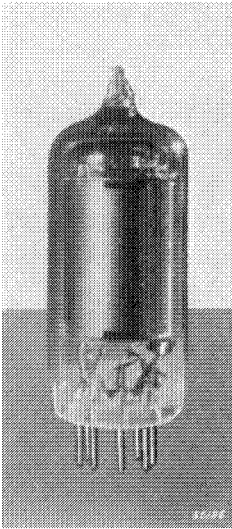


Fig. 1  
The DF 91 (approximately full size).

The DF 91 is a pentode for use as R.F. or I.F. amplifier in battery sets. With 67.5 V on both anode and screen grid, the slope is 0.875 mA/V and the internal resistance 0.25 M $\Omega$ . If the anode voltage be increased to 90 V (67.5 V is the maximum permissible value for the screen grid) the slope and internal resistance are 0.9 mA/V and 0.5 M $\Omega$ , respectively; with 45 V on both anode and screen grid the slope is still 0.7 mA/V, the internal resistance being then 0.35 M $\Omega$ . The capacitance between anode and control grid is less than 0.01 pF.

The filament voltage of this valve is 1.4 V with a filament current of 50 mA; the filament is suitable for parallel as well as series feeding. Directions for series feeding are given in the description of the DAF 91.

The maximum permissible voltages for anode and screen grid are 90 V and 67.5 V, respectively.

The DF 91 is a variable-mu valve and, when control is applied simultaneously to the frequency changer DK 91, a suitable A.G.C. curve can be secured. A method of feeding the screen grids by means of a common resistor is described in the chapter dealing with the DK 91.

Anti-vibration mounting of the holder of the DF 91 is sometimes essential to prevent microphony, and it is usually necessary to provide a screening plate between the anode and control-grid pins, to ensure that the capacitance between these electrodes is not increased by the circuit capacitance.

### TECHNICAL DATA OF THE R.F. PENTODE DF 91

#### Filament data

Heating: direct from battery, rectified A.C., or D.C.; series or parallel feed

#### *In parallel with other valves*

Filament voltage . . .	$V_f$	=	1.4 V
Filament current . . .	$I_f$	=	50 mA

#### *In series with other valves*

Filament voltage . . .	$V_f$	=	1.3 V
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# DF 91

## Capacitances (valve cold)

Input capacitance . . . . .	$C_{g1}$	=	3.6 pF
Output capacitance . . . . .	$C_a$	=	7.5 pF
Between anode and control grid . . . . .	$C_{ag1}$	<	0.01 pF <sup>1)</sup>

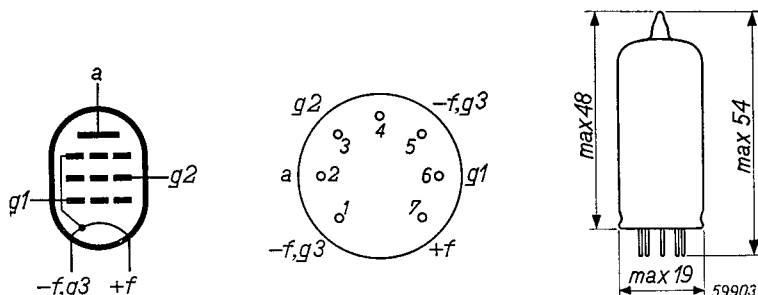


Fig. 2

Electrode arrangement, electrode connections and max. dimensions in mm.

## Operating characteristics for use as R.F. or I.F. amplifier

Anode voltage . . . . .	$V_a$	=	45	67.5	V
Screen grid voltage . . . . .	$V_{g2}$	=	45	67.5	V
Control grid voltage . . . . .	$V_{g1}$	=	0 —10	0 —16	V
Anode current . . . . .	$I_a$	=	1.7 —	3.4 —	mA
Screen grid current . . . . .	$I_{g2}$	=	0.7 —	1.5 —	mA
Mutual conductance . . . . .	$S$	=	700 10	875 10	$\mu\text{A/V}$
Internal resistance . . . . .	$R_i$	=	0.35 >10	0.25 >10	M $\Omega$
Amplification factor: second grid with respect to first grid	$\mu_{g2g1}$	=	11 —	11 —	
Equivalent noise resistance . . . . .	$R_{eq}$	=	— —	20 —	k $\Omega$
Anode voltage . . . . .	$V_a$	=	90	90	V
Screen grid voltage . . . . .	$V_{g2}$	=	45	67.5	V
Control grid voltage . . . . .	$V_{g1}$	=	0 —10	0 —16	V
Anode current . . . . .	$I_a$	=	1.8 —	3.5 —	mA
Screen grid current . . . . .	$I_{g2}$	=	0.65 —	1.4 —	mA
Mutual conductance . . . . .	$S$	=	750 10	900 10	$\mu\text{A/V}$
Internal resistance . . . . .	$R_i$	=	0.8 >10	0.5 >10	M $\Omega$
Amplification factor: second grid with respect to first grid	$\mu_{g2g1}$	=	11 —	11 —	
Equivalent noise factor . . . . .	$R_{eq}$	=	— —	19 —	k $\Omega$

<sup>1)</sup> Measured with external screening.

**Limiting values**

Anode voltage . . . . .	$V_a$	= max.	90 V
Anode dissipation . . . . .	$W_a$	= max.	0.35 W
Screen grid voltage . . . . .	$V_{g^2}$	= max.	67.5 V
Screen grid dissipation . . . . .	$W_{g^2}$	= max.	0.11 W
Cathode current . . . . .	$I_k$	= max.	5.5 mA
Grid current starting point . . . . .	$V_{g1}(I_{g1} = +0.3\mu\text{A})$	= max.	-0.2 V
External resistance between control grid and cathode . . . . .	$R_{g1}$	= max.	3 M $\Omega$

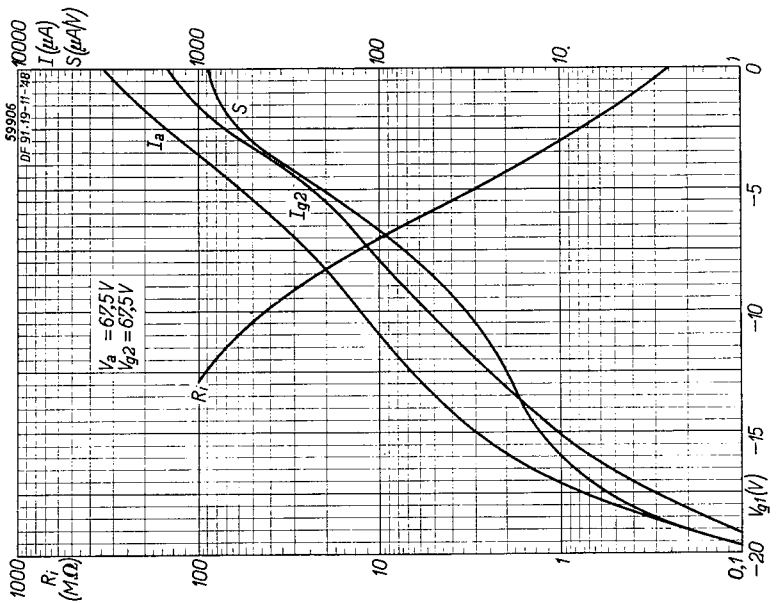


Fig. 3 Anode current ( $I_a$ ), screen grid current ( $I_{sg2}$ ), mutual conductance ( $S$ ) and internal resistance ( $R_i$ ) of the DF 91 as functions of the grid bias ( $V_{g1}$ ). Fig. 3 for  $V_a = V_{sg2} = 45V$ ; Fig. 4 for  $V_a = V_{sg2} = 67.5V$ .

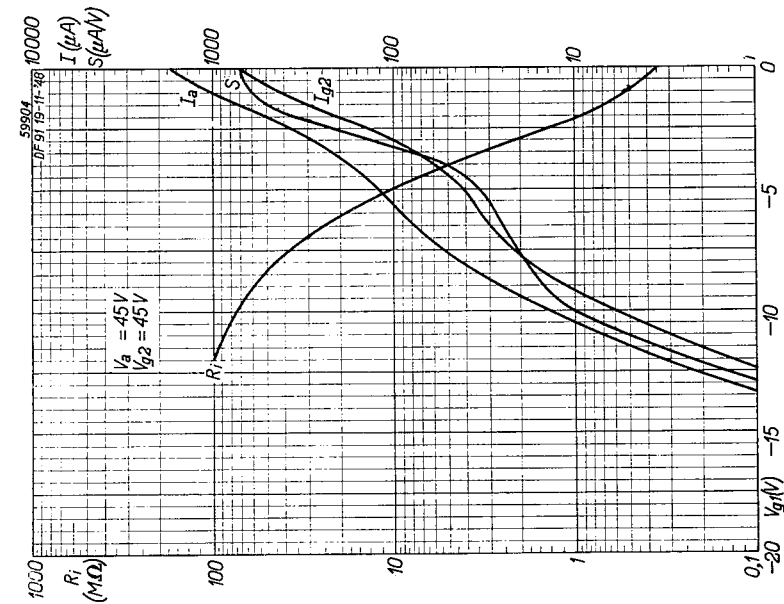


Fig. 4 Anode current ( $I_a$ ), screen grid current ( $I_{sg2}$ ), mutual conductance ( $S$ ) and internal resistance ( $R_i$ ) of the DF 91 as functions of the grid bias ( $V_{g1}$ ). Fig. 3 for  $V_a = V_{sg2} = 45V$ ; Fig. 4 for  $V_a = V_{sg2} = 67.5V$ .

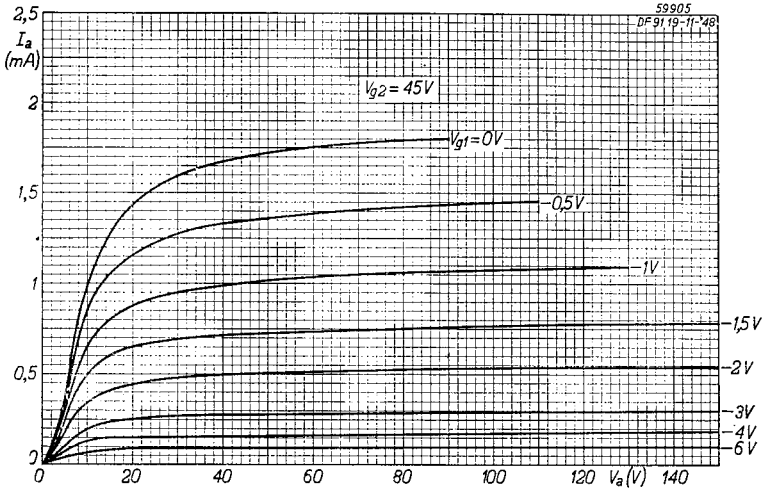


Fig. 5.  $I_a/V_a$  characteristics of the DF 91 with  $V_{g2} = 45$  V.

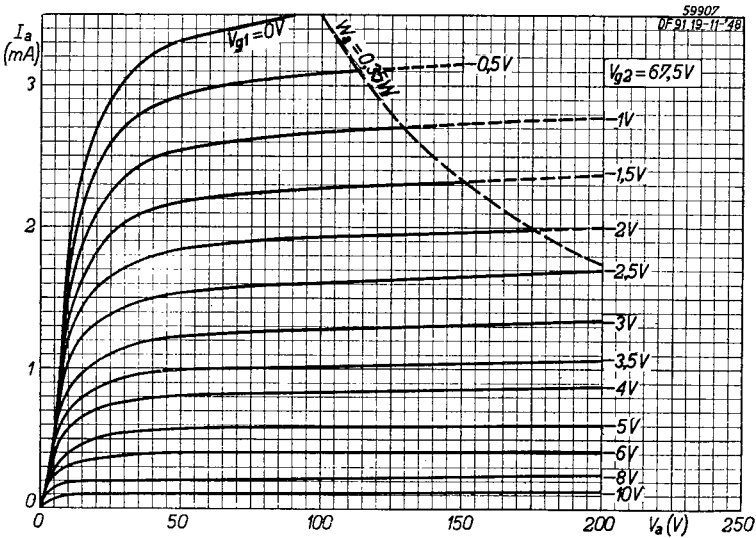


Fig. 6.  $I_a/V_a$  characteristics of the DF 91 with  $V_{g2} = 67.5$  V.

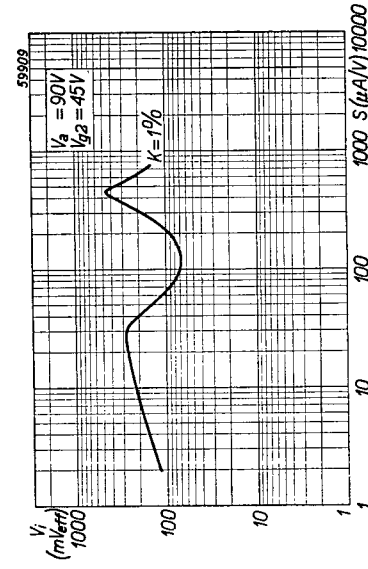
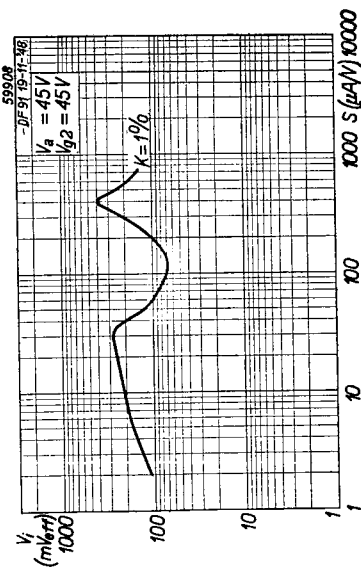
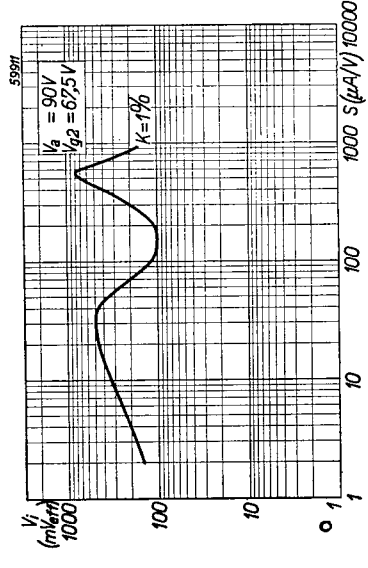
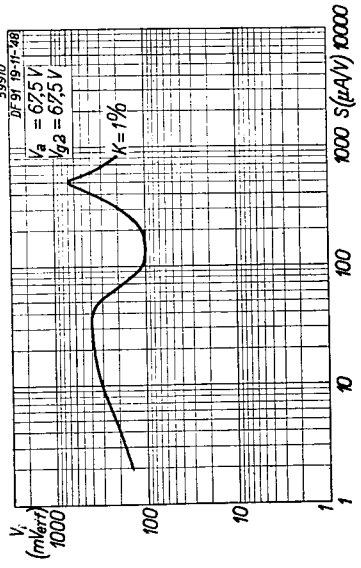


Fig. 8

As Fig 7. Upper : with  $V_a = V_{g2} = 67.5\text{ V}$   
Lower : with  $V_a = 90\text{ V}$  and  $V_{g2} = 67.5\text{ V}$ .

Fig. 7

The input voltage ( $V_i$ ) of an interfering signal producing 1% cross-modulation, as a function of the slope ( $S$ ).  
Upper : with  $V_a = V_{g2} = 45\text{ V}$ . Lower : with  $V_a = 90\text{ V}$  and  $V_{g2} = 45\text{ V}$ .